## PERIPHERAL DRIVERS FOR <br> HIGH-VOLTAGE, HIGH-CURRENT DRIVER APPLICATIONS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 30 V (After Conducting 300 mA )
- Medium-Speed Switching
- Circuit Flexibility for Varied Applications and Choice of Logic Function
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame for Cooler Operation and Improved Reliability
- Package Options Include Plastic Small Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

SUMMARY OF SERIES 55461/75461

| DEVICE | LOGIC | PACKAGES |
| :--- | :--- | :---: |
| SN55461 | AND | FK, JG |
| SN55462 | NAND | FK, JG |
| SN55463 | OR | FK, JG |
| SN75461 | AND | D, P |
| SN75462 | NAND | D, P |
| SN75463 | OR | D, P |

SN55461, SN55462, SN55463 . . . JG PACKAGE SN75461, SN75462, SN75463 ... D OR P PACKAGE (TOP VIEW)



SN55461, SN55462, SN55463 . . . FK PACKAGE (TOP VIEW)


NC - No internal connection

## description

These dual peripheral drivers are functionally interchangeable with SN55451B through SN55453B and SN75451B through SN75453B peripheral drivers, but are designed for use in systems that require higher breakdown voltages than those devices can provide at the expense of slightly slower switching speeds. Typical applications include logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.
The SN55461/SN75461, SN55462/SN75462, and SN55463/SN75463 are dual peripheral AND, NAND, and OR drivers respectively (assuming positive logic), with the output of the gates internally connected to the bases of the npn output transistors.

Series SN55461 drivers are characterized for operation over the full military temperature range of $-55^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. Series SN75461 drivers are characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted) $\dagger$

|  |  | SN55' | SN75' | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ (see Note 1) |  | 7 | 7 | V |
| Input voltage, $\mathrm{V}_{\text {I }}$ |  | 5.5 | 5.5 | V |
| Intermitter voltage (see Note 2) |  | 5.5 | 5.5 | V |
| Off-state output voltage, $\mathrm{V}_{\mathrm{O}}$ |  | 35 | 35 | V |
| Continuous collector or output current (see Note 3) |  | 400 | 400 | mA |
| Peak collector or output current ( $\mathrm{t}_{\mathrm{w}} \leq 10 \mathrm{~ms}$, duty cycle $\leq 50 \%$, see Note 4) |  | 500 | 500 | mA |
| Continuous total power dissipation |  | See Dissipation Rating Table |  |  |
| Operating free-air temperature range, $\mathrm{T}_{\mathrm{A}}$ |  | -55 to 125 | 0 to 70 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range, $T_{\text {stg }}$ |  | -65 to 150 | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Case temperature for 60 seconds, $\mathrm{T}_{\mathrm{C}}$ | FK package | 260 |  | ${ }^{\circ} \mathrm{C}$ |
| Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds | JG package | 300 |  | ${ }^{\circ} \mathrm{C}$ |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | D or P package |  | 260 | ${ }^{\circ} \mathrm{C}$ |

$\dagger$ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTES: 1. Voltage values are with respect to network GND unless otherwise specified.
2. This is the voltage between two emitters $A$ and $B$.
3. This value applies when the base-emitter resistance ( $R_{B E}$ ) is equal to or less than $500 \Omega$.
4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

| PACKAGE | $\mathrm{T}_{\mathrm{A}} \leq 25^{\circ} \mathrm{C}$ <br> POWER RATING | DERATING FACTOR ABOVE $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{A}}=70^{\circ} \mathrm{C}$ <br> POWER RATING | $\mathrm{T}_{\mathrm{A}}=125^{\circ} \mathrm{C}$ <br> POWER RATING |
| :---: | :---: | :---: | :---: | :---: |
| D | 725 mW | $5.8 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ | 464 mW | - |
| FK | 1375 mW | 11.0 mW/ ${ }^{\circ} \mathrm{C}$ | 880 mW | 275 mW |
| JG | 1050 mW | $8.4 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ | 672 mW | 210 mW |
| P | 1000 mW | 8.0 mW/ ${ }^{\circ} \mathrm{C}$ | 640 mW | - |

## recommended operating conditions

|  | SN55' |  |  | SN75' |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOM | MAX | MIN | NOM | MAX |  |
| Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| High-level input voltage, $\mathrm{V}_{\text {IH }}$ | 2 |  |  | 2 |  |  | V |
| Low-level input voltage, $\mathrm{V}_{\text {IL }}$ |  |  | 0.8 |  |  | 0.8 | V |
| Operating free-air temperature, $\mathrm{T}_{\mathrm{A}}$ | -55 |  | 125 | 0 |  | 70 | ${ }^{\circ} \mathrm{C}$ |

## logic symbol $\dagger$


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for $\mathrm{D}, \mathrm{JG}$, and P packages.

## FUNCTION TABLE

(each driver)

| A | B | Y |
| :---: | :---: | :---: |
| L | L | L (on state) |
| L | H | L (on state) |
| H | L | L (on state) |
| H | H | H (off state) |

positive logic:
$Y=A B$ or $\bar{A}+\bar{B}$

## logic diagram (positive logic)


electrical characteristics over recommended operating free-air temperature range

| PARAMETER |  | TEST CONDITIONS $\dagger$ |  | SN55461 |  |  | SN75461 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYPキ | MAX | MIN | TYP\# | MAX |  |
| VIK | Input clamp voltage |  |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}$, | $\mathrm{I}_{\mathrm{I}}=-12 \mathrm{~mA}$ |  | -1.2 | -1.5 |  | -1.2 | -1.5 | V |
| ${ }^{\text {IOH }}$ | High-level output current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \\ & \mathrm{~V}_{\mathrm{OH}}=35 \mathrm{~V} \\ & \hline \end{aligned}$ | $\mathrm{V}_{\mathrm{IH}}=\mathrm{MIN},$ |  |  | 300 |  |  | 100 | $\mu \mathrm{A}$ |
| VOL | Low-level output voltage | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \\ & \mathrm{IOL}=100 \mathrm{~mA} \\ & \hline \end{aligned}$ | $\mathrm{V}_{\mathrm{IL}}=0.8 \mathrm{~V},$ |  | 0.25 | 0.5 |  | 0.25 | 0.4 | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \\ & \mathrm{IOL}=300 \mathrm{~mA} \end{aligned}$ | $\mathrm{V}_{\mathrm{IL}}=0.8 \mathrm{~V},$ |  | 0.5 | 0.8 |  | 0.5 | 0.7 |  |
| 11 | Input current at maximum input voltage | $V_{C C}=M A X$, | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ |  |  | 1 |  |  | 1 | mA |
| ${ }^{\text {IIH }}$ | High-level input current | $V_{C C}=$ MAX, | $\mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
| IIL | Low-level input current | $V_{C C}=$ MAX, | $\mathrm{V}_{1}=0.4 \mathrm{~V}$ |  | -1 | -1.6 |  | -1 | -1.6 | mA |
| ICCH | Supply current, outputs high | $V_{C C}=$ MAX, | $\mathrm{V}_{\mathrm{I}}=5 \mathrm{~V}$ |  | 8 | 11 |  | 8 | 11 | mA |
| ICCL | Supply current, outputs low | $\mathrm{V}_{\text {CC }}=\mathrm{MAX}$, | $\mathrm{V}_{\mathrm{I}}=0$ |  | 56 | 76 |  | 56 | 76 | mA |

$\dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
$\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER |  |  | TEST CONDITIONS |  | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPLH | Propagation delay time, low-to-high-level output |  | $\begin{aligned} & \mathrm{lO} \approx 200 \mathrm{~mA}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $C_{L}=15 \mathrm{pF},$ <br> See Figure 1 |  | 30 | 55 | ns |
| tphL | Propagation delay time, high-to-low-level output |  |  |  |  | 25 | 40 |  |
| t ${ }^{\text {LLH }}$ | Transition time, low-to-high-level output |  |  |  |  | 8 | 20 |  |
| tTHL | Transition time, high-to-low-level output |  |  |  |  | 10 | 20 |  |
| V OH | High-level output voltage after switching | SN55461 | $\mathrm{V}_{\mathrm{S}}=30 \mathrm{~V},$ <br> See Figure 2 | $\mathrm{I}=300 \mathrm{~mA},$ | $\mathrm{V}_{\mathrm{S}}-10$ |  |  | mV |
|  |  | SN75461 |  |  | $\mathrm{V}_{\mathrm{S}}-10$ |  |  |  |

## logic symbol $\dagger$


$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for $\mathrm{D}, \mathrm{JG}$, and P packages.
FUNCTION TABLE (each driver)

| A | B | Y |
| :---: | :---: | :---: |
| L | L | H (off state) |
| L | H | H (off state) |
| H | L | H (off state) |
| H | H | L (on state) |

positive logic: $\mathrm{Y}=\overline{\mathrm{AB}}$ or $\overline{\mathrm{A}}+\overline{\mathrm{B}}$

## logic diagram (positive logic)


schematic (each driver)


Resistor values shown are nominal.
electrical characteristics over recommended operating free-air temperature range

| PARAMETER |  | TEST CONDITIONS $\dagger$ | SN55462 |  |  | SN75462 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYPキ | MAX | MIN | TYPキ | MAX |  |
| $\mathrm{V}_{\text {IK }}$ | Input clamp voltage |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{I}=-12 \mathrm{~mA}$ |  | -1.2 | -1.5 |  | -1.2 | -1.5 | V |
| ${ }^{\mathrm{IOH}}$ | High-level output current | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IL}}=0.8 \mathrm{~V}, \\ \mathrm{~V}_{\mathrm{OH}}=35 \mathrm{~V} & \\ \hline \end{array}$ |  |  | 300 |  |  | 100 | $\mu \mathrm{A}$ |
| VOL | Low-level output voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IH}}=\mathrm{MIN}, \\ & \mathrm{IOL}=100 \mathrm{~mA} \\ & \hline \end{aligned}$ |  | 0.25 | 0.5 |  | 0.25 | 0.4 | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IH}}=\mathrm{MIN}, \\ & \mathrm{l} \mathrm{OL}=300 \mathrm{~mA} \\ & \hline \end{aligned}$ |  | 0.5 | 0.8 |  | 0.5 | 0.7 |  |
| 1 | Input current at maximum input voltage | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}$ |  |  | 1 |  |  | 1 | mA |
| IIH | High-level input current | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
| IIL | Low-level input current | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=0.4 \mathrm{~V}$ |  | -1.1 | -1.6 |  | -1.1 | -1.6 | mA |
| ICCH | Supply current, outputs high | $V_{C C}=M A X, \quad V_{l}=0$ |  | 13 | 17 |  | 13 | 17 | mA |
| ${ }^{\text {I CCL }}$ | Supply current, outputs low | $V_{C C}=\mathrm{MAX}, \quad \mathrm{V}_{1}=5 \mathrm{~V}$ |  | 61 | 76 |  | 61 | 76 | mA |

$\dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
$\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Propagation delay time, low-to-high-level output |  | $\begin{aligned} & \mathrm{l}=200 \mathrm{~mA}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $C_{L}=15 \mathrm{pF},$ <br> See Figure 1 |  | 45 | 65 | ns |
| Propagation delay time, high-to-low-level output |  |  |  |  | 30 | 50 |  |
| Transition time, low-to-high-level output |  |  |  |  | 13 | 25 |  |
| Transition time, high-to-low-level output |  |  |  |  | 10 | 20 |  |
| High-level output voltage after switching | SN55462 | $V_{S}=30 \mathrm{~V},$ <br> See Figure 2 | $\mathrm{l}=300 \mathrm{~mA}$, |  | S-10 |  | mV |
|  | SN75462 |  |  | $\mathrm{V}_{\mathrm{S}}-10$ |  |  |  |

## logic symbol $\dagger$


$\dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for $\mathrm{D}, \mathrm{JG}$, and P packages.
FUNCTION TABLE (each driver)

| A | B | Y |
| :---: | :---: | :---: |
| L | L | L (on state) |
| L | H | H (off state) |
| H | L | H (off state) |
| H | H | H (off state) |

positive logic: $Y=A+B$ or $\bar{A} \bar{B}$

## logic diagram (positive logic)




## electrical characteristics over recommended operating free-air temperature range

| PARAMETER |  | TEST CONDITIONS $\dagger$ | SN55463 |  |  | SN75463 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP\# | MAX | MIN | TYP\# | MAX |  |
| VIK | Input clamp voltage |  | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{I}=-12 \mathrm{~mA}$ |  | -1.2 | -1.5 |  | -1.2 | -1.5 | V |
| ${ }^{\text {IOH }}$ | High-level output current | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IH}}=\mathrm{MIN}, \\ \mathrm{~V}_{\mathrm{OH}}=35 \mathrm{~V} & \\ \hline \end{array}$ |  |  | 300 |  |  | 100 | $\mu \mathrm{A}$ |
| VOL | Low-level output voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IL}}=0.8 \mathrm{~V}, \\ & \mathrm{IOL}=100 \mathrm{~mA} \end{aligned}$ |  | 0.25 | 0.5 |  | 0.25 | 0.4 | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{MIN}, \quad \mathrm{~V}_{\mathrm{IL}}=0.8 \mathrm{~V}, \\ & \mathrm{IOL}=300 \mathrm{~mA} \end{aligned}$ |  | 0.5 | 0.8 |  | 0.5 | 0.7 |  |
| 11 | Input current at maximum input voltage | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V}$ |  |  | 1 |  |  | 1 | mA |
| $\mathrm{IIH}^{\text {H }}$ | High-level input current | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V}$ |  |  | 40 |  |  | 40 | $\mu \mathrm{A}$ |
| IIL | Low-level input current | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=0.4 \mathrm{~V}$ |  | -1 | -1.6 |  | -1 | -1.6 | mA |
| ${ }^{\text {I CCH }}$ | Supply current, outputs high | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{I}}=5 \mathrm{~V}$ |  | 8 | 11 |  | 8 | 11 | mA |
| ICCL | Supply current, outputs low | $\mathrm{V}_{\mathrm{CC}}=\mathrm{MAX}, \quad \mathrm{V}_{\mathrm{l}}=0$ |  | 58 | 76 |  | 58 | 76 | mA |

$\dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
$\ddagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
switching characteristics, $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER |  |  | TEST CONDITIONS |  | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tPLH | Propagation delay time, low-to-high-level output |  | $\begin{aligned} & \mathrm{I}=200 \mathrm{~mA}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $C_{L}=15 \mathrm{pF},$ <br> See Figure 1 |  | 30 | 55 | ns |
| tPHL | Propagation delay time, high-to-low-level output |  |  |  |  | 25 | 40 |  |
| tTLH | Transition time, low-to-high-level output |  |  |  |  | 8 | 25 |  |
| tTHL | Transition time, high-to-low-level output |  |  |  |  | 10 | 25 |  |
| V OH | High-level output voltage after switching | SN55463 | $V_{S}=30 \mathrm{~V},$ <br> See Figure 2 | $\mathrm{l}=300 \mathrm{~mA}$, | $\mathrm{V}_{\mathrm{S}}-10$ |  |  | mV |
|  |  | SN75463 |  |  | $\mathrm{V}_{\mathrm{S}}-10$ |  |  |  |

## PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT


VOLTAGE WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: $\mathrm{PRR} \leq 1 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}} \approx 50 \Omega$.
B. $C_{L}$ includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms for Switching Times


NOTES: A. The pulse generator has the following characteristics: $\mathrm{PRR} \leq 12.5 \mathrm{kHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$.
B. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test

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INSTRUMENTS
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## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead finish/ Ball material <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| JM38510/12908BPA | ACTIVE | CDIP | JG | 8 | 1 | Non-RoHS \& Green | SNPB | N / A for Pkg Type | -55 to 125 | $\begin{aligned} & \hline \text { JM38510 } \\ & \text { /12908BPA } \end{aligned}$ | Samples |
| M38510/12908BPA | ACTIVE | CDIP | JG | 8 | 1 | Non-RoHS \& Green | SNPB | N/ A for Pkg Type | -55 to 125 | $\begin{aligned} & \text { JM38510 } \\ & \text { /12908BPA } \end{aligned}$ | Samples |
| SN75462D | ACTIVE | SOIC | D | 8 | 75 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 75462 | Samples |
| SN75462DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 75462 | Samples |
| SN75462P | ACTIVE | PDIP | P | 8 | 50 | RoHS \& Green | NIPDAU | N / A for Pkg Type | 0 to 70 | SN75462P | Samples |
| SN75462PE4 | ACTIVE | PDIP | P | 8 | 50 | RoHS \& Green | NIPDAU | N / A for Pkg Type | 0 to 70 | SN75462P | Samples |
| SN75463P | ACTIVE | PDIP | P | 8 | 50 | RoHS \& Green | NIPDAU | N / A for Pkg Type | 0 to 70 | SN75463P | Samples |
| SNJ55462FK | ACTIVE | LCCC | FK | 20 | 1 | Non-RoHS \& Green | SNPB | N/A for Pkg Type | -55 to 125 | $\begin{aligned} & \text { SNJ55 } \\ & \text { 462FK } \end{aligned}$ | Samples |
| SNJ55462JG | ACTIVE | CDIP | JG | 8 | 1 | Non-RoHS \& Green | SNPB | N / A for Pkg Type | -55 to 125 | SNJ55462JG | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## OTHER QUALIFIED VERSIONS OF SN55462, SN75462 :

- Catalog : SN75462
- Military : SN55462

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TeXAS

## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> (iameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> W1 $(\mathbf{m m})$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN75462DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

PACKAGE MATERIALS INFORMATION


All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length $(\mathbf{m m})$ | Width $(\mathbf{m m})$ | Height $(\mathbf{m m})$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN75462DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |

## TUBE



## B - Alignment groove width

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T $(\boldsymbol{\mu m})$ | B (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN75462D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN75462P | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| SN75462PE4 | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| SN75463P | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| SNJ55462FK | FK | LCCC | 20 | 1 | 506.98 | 12.06 | 2030 | NA |



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed . 006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.


SOLDER MASK DETAILS

NOTES: (continued)
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


NOTES: (continued)
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

JG (R-GDIP-T8)


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification.
E. Falls within MIL STD 1835 GDIP1-T8
$P(R-P D I P-T 8)$
PLASTIC DUAL-IN-LINE PACKAGE


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001 variation BA.

FK (S-CQCC-N**)
LEADLESS CERAMIC CHIP CARRIER 28 TERMINAL SHOWN


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. Falls within JEDEC MS-004

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